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The correlation between N deficiency and the mechanical properties of the Ti₂AlN_v MAX phase

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Abstract:

The role of X deficiency on the mechanical properties of MAX phases was studied by synthesizing Ti₂AlN by powder metallurgy in stoichiometric sub/extra-stoichiometric nitrogen compositions. XRD analyses and ab initio calculations indicate that nitrogen vacancies result in a lattice contraction predominantly along the c-axis. The elastic moduli and intrinsic hardness of substoichiometric Ti₂AlN_{0.9} measured from nanoindentation tests are shown to be slightly smaller than that of Ti₂AlN. The key mechanical indexes, bulk (B), shear (G) and Young's (E) moduli as well as the hardness variation are calculated in density functional theory, and show different responses depending on the concentration of N vacancies. This joint experimental and theoretical study provides a full understanding of the energetics, chemical bonding, electronic structure, and mechanics of the N deficient MAX phases which would increase the application of nitride ceramics.

Keywords: Nonstoichiometric Ti₂AlN; Anisotropic; Microstructure; Mechanical properties;

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1. Introduction[‡]

MAX phases denoted as M_{n+1}AX_n (n=1-3) are a class of layered hexagonal ternary carbides/nitrides, where M is an early transition metal, A is from group IIIA or IVA element, X is C and/or N. MAX phases exhibit a combination of strong covalent M-X bonds interleaved with A layers through weak M-A bonds.^[1,2] In sharp contradiction with binary carbides/nitrides (hard and brittle, nonmachinable, damage intolerant, and susceptible to thermal shock), MAX phases exhibit machinability, excellent electrical and thermal conductivities, thermal shock and oxidation resistance, stiffness at high temperature and self-lubrication capacity, which bridge the gap between metals and ceramics ^[2-8]. Ti-based MAX phase compounds are used as ohmic contacts on wide-gap semiconductors to achieve high-quality of electronic devices ^[9, 10], and have shown good tolerance to neutron irradiation^[11].

Concerning the crystal structure, MAX phases and MX phases have similar Ti-N and Ti-C chemical bonding characteristics^[12]. In binary transition metal carbide/nitrides, mechanical, chemical and physical properties can be modified by controlling the vacancies in X site (TiC_x (x=0.5-0.98) and TiN_y (y=0.6-1.1)^[12-14]). The introduction of 12.5% of vacancies in TiN has been shown to reduce shear stiffness from 190 GPa to about 150GPa.^[15]However, very few studies related to the X deficiency exist for ternary carbides/nitrides MAX phases, possibly due to the difficulty of controlling the defect concentration compared with the binary TiC/TiN.^[14] For example, Yu at al. reported that the synthesis of pure Ti₂AlC can only be achieved with the 2Ti:1.05Al:0.85C nominal composition by hot isostatic pressing (HIP) at 1400°C/80MPa for 4h. Guo et al. ^[16] demonstrated that single-phased Ti₂AlC_x (x<1) can be fabricated by combustion synthesis starting with 2Ti:Al:0.7C powder

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mixture. The main combustion product is Ti₃AlC₂ if the molar ratio of the reactant mixture is 2Ti:Al:C. Cabioc'h et al. reported that a large nitrogen deficiency in Ti₂AlN can be realized^[17], which provides with an effective means to investigate the effect of X site vacancies on the microstructure and properties of MAX phases. Substoichiometric effects allow modifying and, in some cases, improving their physical properties. For example, Scabarozi et *al.* have shown that substoichiometric Ti₂AlN_{0.95} has a higher resistivity than stoichiometric Ti₂AlN^[18] which suggests that vacancies are strong electron scatters.

The MAX phases are also of interest because the ability to etch away the A atoms enables the synthesis of two-dimensional MXenes.^[2, 19] Notably, nitride MXenes are predicted to exhibit higher capacitance than carbides as the promising capacitive materials^[20], but they have not been widely studied. The control of the N deficiency in MAX phases would thus result in new MXenes.

In the present work, a series of Ti₂AlN_y MAX phases in a wide N concentration (y=0.85-1.05) are synthesized by pressureless sintering. The cell parameters, octahedral and trigonal distortion parameters are determined both by the Rietveld method and calculated by *ab initio* calculations as a function of the vacancy content. Nanoindentation is used to evaluate intrinsic hardness and elastic moduli of Ti₂AlN_{0.9} and Ti₂AlN synthesized by hot isostatic pressing. In order to interpret the experiments, theoretical calculations were performed to determine the N vacancy energetics, the impact on the chemical bonding and electronic structure, and on the mechanical properties. The pioneering correlation between the defects on the X site and the atomic-scale understanding would lay fundamental understanding on this nitride MAX.

2. Experimental details

Powders of Ti (150-250μm, 99.5% purity), Al (45-150μm, 99.5% purity) and AlN (10μm, 98% purity) were used to synthesize stoichiometric and sub/extra-stoichiometric Ti₂AlN_y. In order to study the effect of N content on Ti₂AlN_y lattice parameters, the samples were produced, from different nominal compositions (2Ti:1.05Al:1.05N, 2Ti:1.05Al:1.0N, 2Ti:1.05Al:0.95N, 2Ti:1.05Al:0.90N and 2Ti:1.05Al:0.85N), by pressureless sintering at 1400°C for 0.5h. To investigate the

vacancy effect on X site, on the intrinsic hardness and indentation modulus values, 2Ti:1.05Al:1.0N and 2Ti:1.05Al:0.90N nominal compositions were used and dense samples were produced by hot isostatic pressing (HIP) at 1400°C/80MPa for 4h. The synthesis procedure is detailed in [21]. The powder mixtures used in this study contain an excess of 5 at.% of Al to compensate the loss of aluminum by preferential out-diffusion during the sintering process.

Samples used for nanoindentation tests were thus grinded using SiC paper and then polished with a diamond suspension. Finally, a chemo-mechanical polishing has been performed using a neutral suspension of alumina nanoparticles. Such a chemo-mechanical polishing allows to produce a very flat surface and to avoid any work hardening due to conventional grinding.

Phase identification was performed by X-Ray Diffraction (XRD) using a Bruker D501 diffractometer with Cu-K $_{\alpha}$ radiation. XRD data were refined using the MAUD software [30] in order to extract the lattice parameters of the Ti₂AlN $_{y}$ compounds. Microstructures were examined by Scanning Electron Microscopy (SEM, JEOL 5600LV). Wavelength Dispersive x-ray Spectroscopy (WDS, CAMECA SX100) was used to determine the composition of Ti₂AlN $_{y}$ resulting from HIP treatment.

Nanoindentation tests have been performed using a Nano Hardness Tester (NHT) apparatus (CSM instrument, Switzerland) equipped with a Berkovich indenter. The indenter shape has been carefully calibrated for true penetration depth as small as 20nm both by direct Atomic Force Microscopy (AFM) observation and by indenting fused silica samples with a Young's modulus of 72GPa. A large indentation network of 150 indents was performed for each sample in order to probe different crystal grain orientations. The load-penetration depth curves are recorded for each nanoindentation test, and the hardness and elastic modulus are determined from the elastic unloading curve using the equivalent indenter method^[22, 23]. Different loads (1, 2, 3, 6, 10, 15, 30, 100 mN) corresponding to different penetration depths were used in order to study the hardness variation with penetration depth. SEM observations were carried out to remove from the statistics the hardness and elastic modulus values that have been measured on indents that were not localized on a single MAX phase grain.

3. Theoretical methods

Our theoretical work used density functional theory (DFT) and the Vienna atomic simulation package (VASP)^[24-26]. We used the projector augmented wave method (PAW) and the generalized gradient approximation Perdew-Burke-Ernzerhof functional [27]. The valence electronic configurations were $2s^22p^3$ for N, $3s^23p^1$ for Al, and $3p^63d^34s^1$ for Ti. Geometry optimization utilized 520 eV for the plane wave cutoff energy and convergence criteria of 5×10^{-6} eV for the total energy and 0.01 eV/Å^{-1} for the absolute maximum force. Γ centered $15 \times 15 \times 1$ k-point grids for Brillouin zone (BZ) integration gave convergence to approximately 3 meV/atom. The special quasi-random structure (SQS) method^[28] was employed to describe N deficient structures in 4×4×1 supercells containing 128 atoms. 5×5×1 k-point grids were used for these cells. Unless otherwise noted, all lattice parameters and atomic positions were fully relaxed self-consistently. The Electron Localization Function (ELF)^[29, 30] was calculated from the Kohn Sham orbitals.

The stress–strain method was employed to compute elastic constants, c_{ij} . Related mechanical properties were calculated on the basis of the these properties (in Voigt approximation^[31]).. The bulk modulus, B and shear modulus, G and Young's modulus, E of polycrystalline aggregates are derived by :

$$G_V = \frac{1}{15} \left((2c_{11} + c_{33} - c_{12} - 2c_{13}) + \frac{1}{5} (2c_{44} + c_{66}) \right)$$

$$B_V = \frac{2}{9} \left(c_{11} + c_{12} + 2c_{13} + \frac{1}{2} c_{33} \right)$$

$$E = \frac{9BG}{3B + G}$$

4. Results and discussion

4.1 Microstructural characterizations

Fig.1(a-e) shows the back-scattered microstructural morphologies of Ti₂AlN_y fabricated by pressureless sintering at 1400°C for 0.5h from 2Ti:1.05Al:yN (y=0.85,0.9,0.95,1.0 and 1.05) nominal compositions. We can distinguish that the Ti₂AlN grain size decreased with increasing N content in the starting powders. For all samples, EDS analyses show that the overall Ti/Al ratio is 2:0.99, very close to 2:1, which indicates the loss of approximately 5 at.% of the aluminum during reactive

sintering. Starting with 2Ti:1.05Al:0.85N nominal composition [Fig.1(a)], titanium aluminide (Ti_xAl_y) is detected in addition to the desired Ti₂AlN_y MAX phase. Starting with 2Ti:1.05Al:0.9N [Fig.1(b)], 2Ti:1.05Al:0.95N [Fig.1(c)], and 2Ti:1.05Al:1.0N [Fig. 1(d)] nominal compositions, only Ti₂AlN_y is observed; no impurities are detected. Starting with 2Ti:1.05Al:1.05N nominal composition [Fig.1(e)], SEM observations coupled with EDS analyses confirm that Ti₄AlN_y (Ti/Al=4), Ti₂AlN_y (Ti/Al=2) and some Al₂O₃ (white dots) are formed. XRD results confirm SEM/EDS analyses. Indeed, XRD pattern shown in Fig.1(f) demonstrates that only Ti₂AlN_y peaks are detected for N content in the range 0.9-1.0. In addition to Ti₂AlN_y, titanium aluminides (Ti_xAl_y) and Ti₄AlN_y are respectively detected starting with 2Ti:1.05Al:0.85N and 2Ti:1.05Al:1.05N nominal compositions.

Comparing the XRD patterns, the XRD peak corresponding to (006) planes progressively shifts towards higher 20 values when N content (y) increases, while the (100) peak shift is less significant. In reference to the interplanar spacing calculation in hexagonal system shown in Equation 1,interplanar spacings (d) for (006) and (100) planes are $\frac{c}{8}$, and $\frac{3a}{4}$, respectively.

$$d = \frac{1}{\frac{4}{3}\sqrt{\frac{(h^2 + hk + k^2)}{a^2} + \frac{l^2}{c^2}}}$$
(1)

Herein, we find that N vacancy has a stronger effect on the c lattice parameter than on a

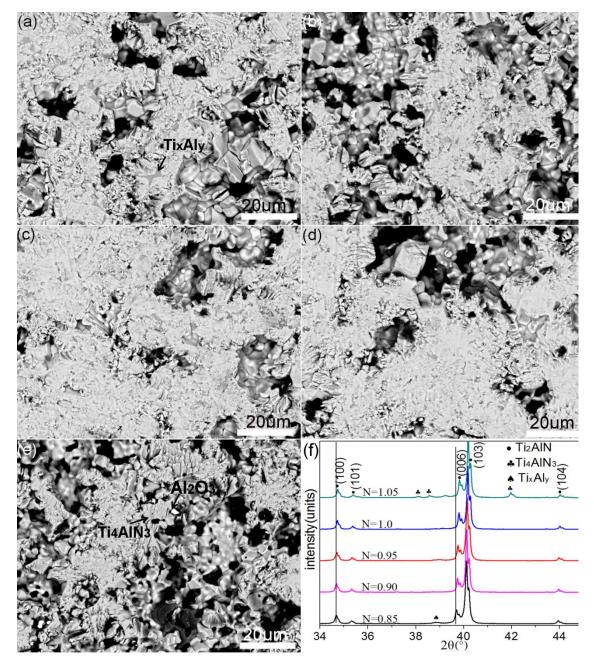


Fig.1: (a-e) Morphologies of Ti_2AlN_y samples produced by pressureless sintering at 1400°C for 0.5h from 2Ti:1.05Al:yN (y=0.85,0.9,0.95,1.0 and 1.05) nominal compositions; (f) XRD patterns of different mixtures sintered at 1400°C for 0.5h. The (hkl) indexed peaks correspond to the Ti_2AlNy MAX phase.

The lattice parameters (LPs) of Ti_2AlN_y as a function of N content, measured from Rietveld refinement of the XRD data using MAUD software, and calculated using ab initio calculations, are summarized in Table I and shown in Fig. 2a. Similar to the findings by Cabioch et al.^[17], the volumes of the unit cell remain almost constant independent of y, while different variations for a and c LPs are clearly found: both experimentally and theoretically, the lattice contraction of Ti_2AlNy is strongly

anisotropic, namely, a parameter slightly increases about 0.0062 Å while c parameter decreases about 0.0488 Å as the N content increases from 0.85 to 1.05. From Fig. 2b, the variation of the c/a ratio (about 0.56%) as a function of N content and consistency with the calculations indicates that the N vacancies are primarily randomly distributed. The calculated trends of the LPs well reproduce the experimental measurements.

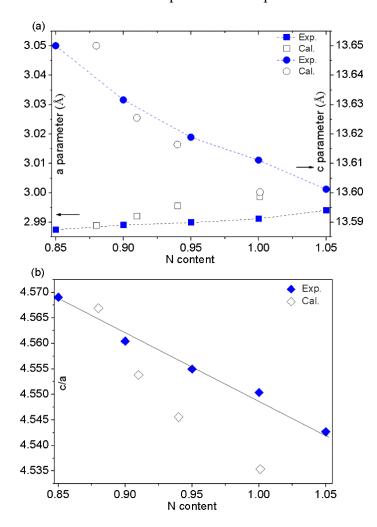


Fig.2. (a) Variation of the a and c -LPs as a function of nitrogen content in the Ti₂AlN_y compounds from XRD experiments (blue) and ab initio calculations (white). (b) the c/a ratio versus N content. Error bars for lattice parameters being too small to be clearly observable (Uncertainties of 5×10^{-4} Å and 5×10^{-3} Å was typically obtained for a and c parameters.

The MAX crystal unit cell, as shown in Fig.3a, can be considered as constituted of [M₆X] octahedrons and [M₆A] trigonal prisms^[32, 33] allowing us to describe the "211" MAX phases^[34]. A cubic octahedron is the unit block of the binary MX, but the fourfold axis is absent in ternary MAX that results in a relaxation owing to the lowered

symmetry. The parameter O_d , defined as the ratio of the distances between two faces not in the basal planes (d_1) and two opposite faces contained in the basal planes $(d_2)^{[33]}$, can be used to estimate the non-cubic distortion of the octahedron. It is given by:

$$O_d = \frac{d_1}{d_2} = \frac{\sqrt{3}}{2\sqrt{4Z_{Ti}^2(\frac{c}{a})^2 + \frac{1}{12}}}$$
 (2)

The distortion parameter P_d , defined as the ratio of the M-M distance and the M-A distance^[32], allows estimating the distortion of the trigonal prism. It is given, in either 211 or 312 MAX phases, by:

$$P_d = \frac{1}{\sqrt{(\frac{1}{4} - Z_{Ti})^2 (\frac{c}{a})^2 + \frac{1}{3}}}$$
(3)

For an ideal packing of hard spheres of equal diameter, a ratio for c/a as of $8 \times \sqrt{\frac{2}{3}}$ will be satisfied, and for an ideal octahedron (cubic) and trigonal prism, a unity for both O_d and P_d should also be reached. From the position of Ti atoms (Z_{Ti}), a and c lattice parameters measured above, both O_d and P_d were experimentally determined and plotted as a function of the N content in Ti₂AlN_y in Fig.3b. Obviously, the relative distortion of the prism is similar to the one of the octahedron whatever the N content in Ti₂AlN_y, and the variations of O_d and P_d are very weakly dependent on the N content, and showing the linearly increasing with the N content in both calculations and experiments. The underestimation of O_d and vice versa for P_d might be due to the typical under-bonding of PBE functional in DFT. As shown in Table 1, the distance of Ti-Al monotonically decreases with the increase of N content, but the variation of Ti-N distance is not evident, indicating the different interactions between TiN and Al (weak) as well as the Ti and N (weak). To clarify how the N deficiency inside of Ti₆C octahedra impacts the Ti-Al & Ti-C bond as well as mechanical properties, we carry out the following work.

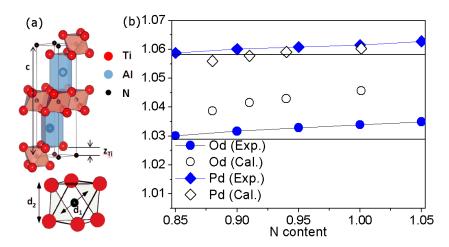


Fig. 3: (a) The unit cell of the Ti₂AlN phase with [Ti₆N] octahedrons (red) and [Ti₆Al] trigonal prisms (blue) represented with VESTA [34]. (b) the Octahedron (O_d , circles) and trigonal prism (P_d , squares) distortion parameters versus N content in Ti₂AlN_y.

4.2 Hardness and Young's moduli

To investigate the influence of N vacancies on Ti₂AlN_y mechanical properties, nanoindentation tests were conducted on samples HIPed from 2Ti:1.05Al:0.9N (Fig.4a) and 2Ti:1.05Al:1.0N (Fig.4b) nominal compositions. WDS analysis indicates that the chemical composition of the Ti₂AlN_y end-products is similar to the starting powders composition. The Al₂O₃ content, determined by image analysis (from ImageJ software) is about 2vol.% starting with 2Ti:1.05Al:1.0N nominal composition and close to 0 starting with 2Ti:1.05Al:0.9N. Here, the Al₂O₃ content decreases with the decrease of the AlN content in the initial reactant powder mixture. Thus, the presence of alumina is likely resulting from the oxidation of AlN starting powders.

Fig.4c shows the variation of the intrinsic hardness and elastic modulus as a function of the indenter penetration depth for Ti₂AlN_{0.9} and Ti₂AlN_{1.0} compounds. The standard deviations result from an average over different grain orientations. From Fig. 4c, one can notice that hardness values strongly decrease with increasing penetration depth. Such an Indentation Size Effect (ISE) [35] was also observed in Ti₃SnC₂[36], Ti₃AlC₂[37] and Ti₃(Al_{0.8}Sn_{0.2})C₂[37] MAX phase materials. From Fig. 4c, Ti₂AlN_y nanoindentation modulus remains constant whatever is the penetration depth: the elastic modulus values of Ti₂AlN_{0.9} and Ti₂AlN are respectively 268±10 GPa and 278±10 GPa. Such a result demonstrates that the indenter shape calibration is correct

and, consequently, that the ISE discussed above is not an artefact due to errors in indenter shape calibration.

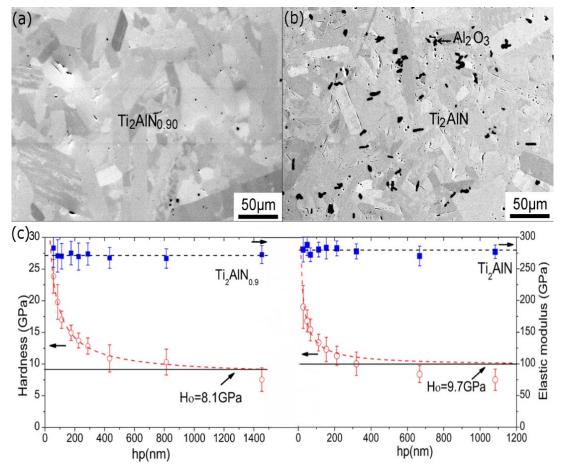


Figure 4: Typical back-scattered images of Ti₂AlN_{0.90} (a) and Ti₂AlN (b) samples HIPed at 1400°C and 80MPa for 4 h from 2Ti:1.05Al:0.90N and 2Ti:1.05Al:1.0N. Hardness (circles) and nanoindentation modulus (squares) of Ti₂AlN and Ti₂AlN_{0.9} (c) as a function of the indenter penetration depth. The red dotted line fits the ISE using the function proposed in the Nix and Gao model^[38].

The variation of the hardness values is well-fitted by the same function as that proposed in the Nix and Gao model ^[38], except for the higher load (i.e.: 100 mN). From the fit shown in Fig. 4c, one can deduce that the intrinsic hardness values of Ti₂AlN_{0.9} and Ti₂AlN are respectively 8.1 and 9.7 GPa. For the 100 mN load, the size of the indents is in the order of the mean grain size. In that case, several grains are involved in the deformation process and grain boundaries play an important role in macroscopic deformation, as reported by Tromas et *al.* ^[36]. For such high loads, nanoindentation conditions (loads, depth of the indent, number of grains involved in

the deformation,...) are close to microindentation ones and the hardness values are similar to those reported in microindentation experiments.^[39]

Up to now, the effect of vacancies on the mechanical properties of MAX phases has not been investigated. The hardness values of TiC_x and TiN_y decrease with increasing vacancy content^[13, 15]. In substoichiometric TiN_y, the integrated density of states(DOS) demonstrates that Ti(3*d*)-N(2*p*) bonding states are reduced in the presence of vacancies, leading to a weakened bond strength, shear strength and hardness^[40]. Furthermore, it is predicted that the introduction of 12.5% of vacancies in TiN_y significantly reduces its shear stiffness from 190 GPa to less than 150GPa ^[15], agreeing well with the experimental results ^[41]. A similar trend has been measured experimentally in TiC_x ^[13]. For the ternary nitride Ti₂AlN, intuitively, the N vacancies would play a softening role in the mechanical properties.

From Table II, the C_{ij} are reduced due to the weaker M-X bonding, as the concentration of N vacancies is increased. In the hexagonal lattice, the C_{II} is the in-plane elastic response, which is larger than C_{33} derived by the out-of-plane distortion, indicating the average bonding along the in-plane is stronger than the out-of-plane. It is indeed true, somehow determined by the layered structure. However, with higher N deficiency, these two constants become similar as the MAX lattice is becomes more isotropic, which is also shown in Fig. 2. When C_{33} is close to or smaller than C_{II} , it might be feasible to break the M-A-M bonds significantly damaging the M-X-M bonds^[42, 43]. This would open a new route to obtaining the derivative 2D MXenes with clean surfaces by means of mechanical exfoliation, instead of the currently chemical etching processes that lead to complicated surface terminal structures and compositions.

Table I. Lattice parameters, Ti-Al and Ti-N distances (R), Wyckoff position of Ti atom (z_{Ti}), and the volume of the unit cell (V), and the formation energy of N vacancy (E_f) of Ti₂AlN_y (y: 0.85-1.05). The relative volume changes in theory are shown in the parenthesis.

N _y	LP (Å)	$R_{ ext{Ti-Al}}(\mathring{\mathbf{A}})$	$R_{\text{Ti-N}}(\mathbf{\mathring{A}})$	$z_{ m Ti}$	V (ų)	$E_f(eV)$
N _{0.88} (Cal.)	a=2.99669	2 920	2.094	0.00574	10(074(0 150/)	0.59
	c=13.6373	2.830	2.084	0.08564	106.074(0.15%)	0.58
N _{0.85} (Exp.)	a = 2.9875	2.822	2.090	0.08641	105.506	
	c= 13.6510	2.822	2.090	0.08041	103.300	
N _{0.91} (Cal.)	a=2.99877	2.829	2.084	0.08561	106.129(0.19%)	0.86
	c=13.6255	2.029	2.064	0.08301	100.129(0.1970)	0.80
N _{0.90} (Exp.)	a = 2.9891	2.820	2.090	0.08642	105.477	
	c = 13.632	2.020		0.08042	103.477	
N _{0.94} (Cal.)	a=2.99754	2.837	2.086	0.08564	106.068(0.14%)	1.14
	c=13.3140	2.037		0.00504	100.000(0.1470)	1.17
N _{0.95} (Exp.)	a = 2.9899	2.818	2.089	0.08643	105.435	
	c= 13.6189	2.010	2.00)	0.000-13	103.433	
N _{1.0} (Cal.)	a=2.99889	2.828	2.086	0.08557	105.918	
	c=13.6002	2.020	2.000	0.00337	103.910	
N _{1.0} (Exp.)	a=2.99252	2.818	2.090	0.08643	105.550	
	c= 13.6111	2.010		0.00013	103.330	
N _{1.05} (Exp.)	a = 2.9937	2.817	2.090	0.08644	105.566	
	c=13.6012	2.01/	2.090	0.00077	103.300	

While the shear, bulk and Young's moduli are steadily suppressed with the increasing N vacancy concentration, the three moduli show different magnitudes of response of 13.1%, 7.3%, 11.7%, respectively. Experimentally, for pristine Ti₂AlN, the Young's modulus was found to be 278 ± 10 GPa, which is in a very good agreement with the result obtained by Resonant Ultrasound Spectroscopy (RUS) on a Ti₂AlN bulk polycrystalline sample ($E\sim277$ GPa^[44]) and 270 ± 20 GPa in another independent measurement by nanoindentation ^[45]. Note that the calculated E of Ti₂AlN with varying

N vacancies are all falling into the regime between 258.2 and 293.1 GPa, which is in the line with the above measurements. We concluded that the perturbation of mechanical properties by N vacancies are different, and the incompressibility is the least affected.

4.3 ab initio calculations

As discussed above, the combination of metallic and ceramic characteristics in MAX phases provide us with opportunities in many applications, where the formation of defects, their dynamics, and the consequences for the mechanical properties are critical. The formation energy for the varying N vacancies E_f was defined as $E_f = (E_v + n\mu_N - E_p)/16$, where E_v denotes the total energy of Ti₂AlN phase with N vacancies, μ_N is the chemical potential for a single N atom as of the $\frac{1}{2}$ N₂ gas molecule, E_p stands for the total energy of the pristine Ti₂AlN, and the n is the number of N vacancies in the supercell. Here, we consider the formation energy per unit cell by the division over the size of the supercell, 16. The formation energies of N vacancy in Ti₂AlN are positive, which is similar to the finding of N vacancy in Ti₄AlN₃. [46] It is thus demonstrated that the N vacancies are energetical costly. Moreover, the formation energy of N vacancies in the lower densities are higher than for higher ones.

Having the energetics of the N vacancy formation, we continue to elucidate the mechanical properties and the N vacancies induced changes. Here, we employed two widely used hardness models, $H_{v,Chen}$ [47] and H_{v} [48] to analyze both defect-free and the deficient Ti₂AlN. Note that Pugh's modulus ratio (k) defined as defined as G/B, as the indicator of a material's brittleness, is usually taken into account, and the above two models are expressed as:

$$H_{v,Chen} = 2(k^2G)^{0.585} - 3$$
 (4)

$$H_{v,Tian} = 0.92k^{1.137}G^{0.708}$$
 (5)

We find that in the above two models the hardness is ~20 GPa and decreases monotonically with greater N deficiency. The reduction magnitude of $H_{v,Chen}$ & $H_{v,Tian}$ are about 16% and 10% from the pristine to the highest N deficient MAX phase. In Eq. (4-5), the exponential of k, G are the key to deduce different slope of the change, but the overview of the moduli and hardness of nitride MAX provides with a clear insight to

the role of the N deficiency. Overall, the drop of the hardness by introducing the N deficiency is not showing a dramatic change in strong contrast to the binary nitrides.

Table II. The calculated elastic constants C_{ij} and the derived shear moduli, G, bulk moduli, B, Young's moduli, E and hardness, H (GPa).

MAX	C_{II}	C_{12}	C_{I3}	C_{33}	C_{44}	G	В	E	$H_{v,Chen}$	$H_{v,Tian}$
Ti ₂ AlN _{0.88}	277.1	71.8	84.7	277.1	119.1	107.1	145.9	258.2	18.4	24.3
$Ti_{2}AlN_{0.91}$	272.1	74.0	84.9	283.6	121.1	107.8	146.1	259.7	18.6	24.4
$Ti_2AlN_{0.94}$	306.9	72.6	85.1	295.3	126.7	117.1	154.9	280.6	20.3	25.9
Ti ₂ AlN	317.9	71.1	87.8	288.9	133.1	123.2	157.5	293.1	22.0	27.0

It is well known that the bonding in the MAX phases are a combination of covalent, ionic and metallic bonding. To quantify the chemical bonding characters of Ti_2AIN , we compare the ELF in both the N defect free and deficient ($N_{0.90}$) MAX phases in Fig.5. In Fig.5(a), the predominate Ti-N bond shows a mixture of covalency (the blue bridge feature) and ionicity (the red spheres on N that gain extra electrons from Ti). For the Ti-Al bond, there is no evident covalent bonding but near the Ti surface, a red triangle electronic cloud appears and represents the Ti-Al bonding. This strong localized feature illustrates that the Ti-Al bonding more ionic feature, and neither covalent (showing shared electrons) nor a metallic (the level of localization would be about 0.5). Moreover, in Fig. 5(b), the two N vacancies marked by black circles bring about the expansion of Ti-N block because of lack of chemical bonding. We could also observe a slight change within the interlayer spacing where the arrow pointed. It is thus found that the Ti-N block is suppressed in the N-poor regime, and the interlayer interactions are accompanied to be weakened by N vacancies.

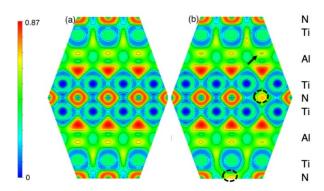


Fig. 5 : 2D cut of the electronic localization function of (a) pristine Ti₂AlN in the miller indices (-111), (b) 2D cut of ELF of Ti₂AlN_{0.90} the view) with the miller indices of (-110) for capturing the defects (marked by spheres) and the changes in the interlayer spacing is marked by arrow. Note that the colour bar on the left represents the level of localization.

We unravel the physical origin behind the electronic properties based on the two series of bonding: Ti(3d)-N(2p) and Ti(3d)-Al(3p). First of all, the primary characteristics of the chemical bonding could be deduced from the vacancy free MAX phase: i) the Fermi energy is dominated by Ti(3d) states, and the valley shaped DOS near the vicinity of Fermi energy is present. ii) The strong covalent bond is on the Ti(3d)-N(2p) hybridization is primarily situated between [-7, -6] & [-6, -4] eV with a pseudo-gap about -5.8 eV as a result of the band splitting. iii) The hybridization of Ti(3d)-Al(3p) states located at -2 and -1.4 eV is weaker intensity and also in higher energy than those of Ti(3d)-N(2p). In general, for N deficient MAX, the Ti(3d)-N(2p) hybridization states are become more broadened in contrast to the pristine MAX, due to the band splitting originating from the symmetry breaking. Moreover, although lacking hybridization around -6 eV, the primary Ti-N hybridization peaks between -5 and -4 eV do not change much with lower N. One might also notice that the a splitting width of 0.6 eV is maintained as N_v drops to 0.88, showing a width of about 0.5 eV. For Ti-Al, a similar tendency is also observed, where the two hybridizations near -2 and -1 eV does not experience an absence. We therefore suggest that MAX phases are a unique class of ceramic able to tolerate N deficiency. The methodology of synthesizing the controllable N concentration of MAX phase, would stimulate the development of nitrides MAX and MXenes in substoichiometry. Our results show that N deficiency in ternary MAX phase leads to a slow reduction of the bond lengths and

mechanical properties, particularly the hardness, resulting in smaller changes than the binary TiN_y ^[15, 41].

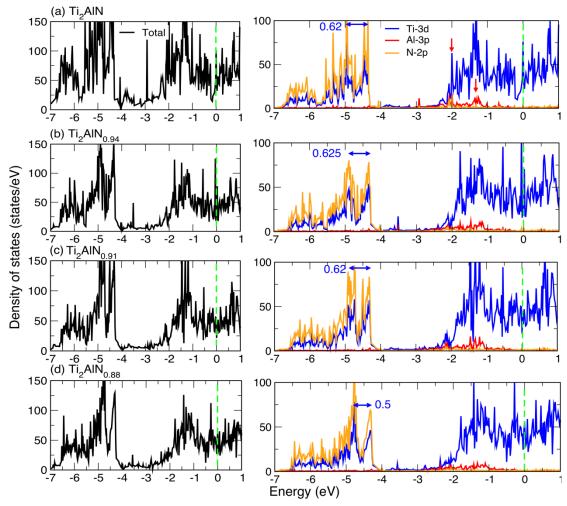


Fig. 6 The total and projected DOS of Ti₂AlN and N deficient MAX phases: (a) Ti₂AlN, (b) Ti₂AlN_{0.94}, (c) Ti₂AlN_{0.91}, (d) Ti₂AlN_{0.88}. The total DOS (left side) is represented by black curves, and the projected DOS (right side) for Ti (3d), Al (3p), and N (2p) states is shown in blue, red and orange, respectively.

5. Conclusions:

In order to reveal the relation between the X deficiency and the mechanical properties of MAX phase for potential structural materials and other applications, Ti₂AlN was synthesized with varying N vacancy concentration by pressureless sintering and hot isostatic pressing. XRD and SEM prove that Ti₂AlN could be synthesized with up to 15% N sub-stoichiometry. The reported method will promote the development of N deficient MAX and MXenes. XRD and *ab initio* calculations reveal that the lattice contraction of Ti₂AlN_y is mainly along the *c*-axis. The correspondence between the XRD and calculations indicates that the N vacancies are not highly ordered and are randomly distributed.

The elastic modulus and intrinsic hardness of substoichiometric Ti₂AlN_{0.9} (268GPa and 8.1GPa respectively) are shown to be smaller than that of Ti₂AlN (278GPa and 9.7GPa respectively). Overall the variation of moduli and hardness with up to 10% N deficiency is small in magnitude compared to the stoichiometric materials both experimentally and theoretically, confirming that the Ti₂AlN exhibits a great potential for tolerating N defects. *Ab initio* calculations demonstrate that both Ti-N and Ti-Al bonding exhibit only a slight weakening by the N deficiency.

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